# New Jersey Semi-Conductor Products, Inc.

20 STERN AVE.

SPRINGFIELD, NEW JERSEY 07081

U.S.A.

TELEPHONE: (973) 376-2922

(212) 227-6005

FAX: (973) 376-8960

## 1N55A GOLD BONDED GERMANIUM DIODE

#### **FEATURES**

Low forward voltage drop—low power consumption
Thirty years of proven reliability—one million hours mean time between failures (MTBF)
Very low noise level
Metallurgically bonded

## ABSOLUTE MAXIMUM RATINGS (at 25 °C, unless otherwise specified)

Peak Inverse Voltage

150 Volts

Peak Forward Current

500 mA

**Operating Temperature Range** 

- 65 °C to 85 °C

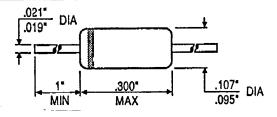
Average Power Dissipation

80 mW

### **ELECTRICAL CHARACTERISTICS**

	Symbol	Conditions	Min	Max	Unit	1*0	
Peak Inverse Voltage	PIV	1 mA	150		V	25 ℃	
Reverse Current	lr	150 V		500	μΑ	25 °C	
Forward Voltage	Vf	4 mA		1	V	25 °C	
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#### MECHANICAL



NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

**Quality Semi-Conductors**